

SSI 32R104C, 32R104CL, 32R104CM, 32R104CLM, 32R108, 32R122 4-Channel Thin Film Read/Write Device

August, 1988

The "M" version is functionally identical to the standard SOL device, except that the pinout is the mirror image to simplify multi-chip layouts.

DESCRIPTION

The SSI 32R104 is a monolithic bipolar integrated circuit for use in high performance disk drive systems where it is desirable to locate the control circuitry directly on the data arm. Each circuit controls four heads and has three modes of operation: Read, Write and Idle.

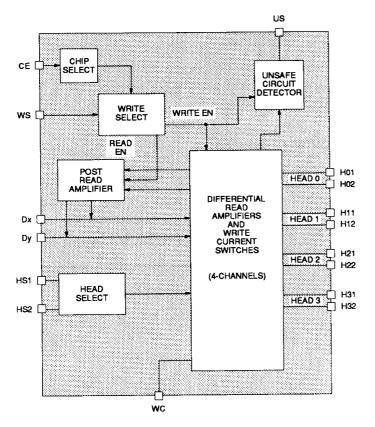
The SSI 32R104L is a low-noise version of the SSI 32R104 with all other parameters identical. Both are available in 24-pin flatpack, and 24-pin small outline (SOL) packages.

The SSI 32R108 and SSI 32R122 are identical in performance to the SSI 32R104. The SSI 32R108 is packaged in a 24-pin DIP package, while the SSI 32R122 is packaged in a 22-pin DIP.

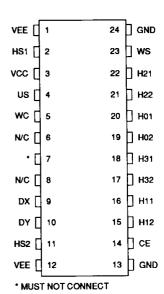
FEATURES

- IBM 3350 compatible performance
- IBM compatible power supply voltages and logic levels
- Four read/write channels
- Safety circuits

BLOCK DIAGRAM



PIN DIAGRAM



32R104, 32R108 Pinout

CAUTION: Use handling procedures necessary for a static sensitive component.

CIRCUIT OPERATION

WRITE MODE

In the write mode, the circuit functions as a current gate. Externally supplied write current is gated by the state of the head select and data inputs to one side of one head. Head voltage swings are monitored by the head transition detect circuit. Absence of proper head voltage swings, indicating an open or short on either side of the head or absence of write current, will cause a fault current to flow into the unsafe pin.

READ MODE

In the read mode, the circuit functions as a low noise differential amplifier. The state of the head select inputs determines which amplifier is active. Data is differentially read from one of four heads and an open collector differential signal is put across the Data X and Data Y pins. If a fault condition exists such that write current is applied to the chip when the chip is in read mode, the write current will be drawn from the unsafe pin and the fault will be detected.

HEAD SELECT TABLE

| HEAD SELECTED | HS2 | HS1 |
|---------------|-----|-----|
| 0 | 1 | 1 |
| 1 | 1 | 0 |
| 2 | 0 | 1 |
| 3 | 0 | 0 |

ELECTRICAL CHARACTERISTICS

Unless otherwise specified, $5.7 \le VCC \le 6.7$, $-4.2 \le VEE \le -3.8$, $0^{\circ} \le Tj$, $\le 110 {\circ}C$.

ABSOLUTE MAXIMUM RATINGS

Operation above absolute maximum ratings may permanently damage the device.

| PARAMETER | RATING | UNIT |
|------------------------------|----------------------|------|
| Positive Supply Voltage VCC | 7.0 | V |
| Negative Supply Voltage, VEE | -5.5 | V |
| Storage Temperature | -65 to 150 | °C |
| Input Voltages | | |
| Head Select (HS) | VEE -0.3 to + 0.3 | V |
| Unsafe (US) | -0.3 to VCC +0.5 | V |
| Write Current (WC) | VEE -2 to + 0.3 | V |
| Data (Dx, Dy) | VEE -0.3 to + 0.3 | V |
| Chip Enable (CE) | VEE -0.3 to VCC +0.5 | V |
| Write Select (WS) | -0.3 to VCC + 0.3 | V |

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POWER SUPPLY

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNIT |
|-------------------------------|------------|------|-----|----------|------|
| Positive Supply Current (ICC) | Read/Write | 11.5 | | 23 | mA |
| Positive Supply Current (ICC) | Idle | | | 75 + ICE | mA |
| Negative Supply Current (IEE) | Read/Write | | | 70 | mA |
| Negative Supply Current (IEE) | Idle | | | 52 | mA |

LOGIC SIGNALS

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNIT |
|----------------------------------|---|----------|-----|----------|----------|
| Chip Enable Low voltage (VLCE) | Read/Write | 0.0 | | 0.7 | V |
| Chip Enable High Voltage (VHCE) | Idle | VCC -1.0 | | VCC +0.3 | V |
| Chip Enable Low Current (ILCE) | VCE = 0.0V | -1.45 | | -0.47 | mA |
| Chip Enable High Current (IHCE1) | VCE = VCC - 1.0 | -350 | | -100 | μΑ |
| Chip Enable High Current (IHCE2) | VCE = VCC + .3V | | | +100 | μΑ |
| Write Select High Voltage (VHWS) | Write/Idle | 3.2 | | 3.8 | V |
| Write Select Low Voltage (VLWS) | Read/Idle | -0.1 | | 0.1 | V |
| Write Select High Current (IHWS) | Write/Idle, VWS = 3.8V | | | | |
| | Transition unsafe current off | 0.6 | | 3.2 | mA |
| | Transition unsafe on | 0.6 | | 4.2 | mA |
| Write Select Low Current (ILWS) | Read/Idle, VWS = 3.8V | | | 0.1 | mA |
| Head Select High Voltage (VHHS) | | -1.12 | | -0.72 | V |
| Head Select Low Voltage (VLHS) | | -2.38 | | -1.51 | ٧ |
| Head Select High Current (IHHS) | | | | 240 | μА |
| Head Select Low Current (ILHS) | | | | 60 | μА |
| Total Head Input Current | Sum of all head input currents with IWC = 0 | | | | |
| | Write, VCT = 3.5V | | | 3.7 | mA |
| | Read, VCT = 0.0V | | | 0.16 | mA |
| | Idle | | | 1.25 | mA |

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READ MODE

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNIT |
|--------------------------------|--|-------|-----|-------|-------|
| Differential Gain | Vin = ImV p-p, 0VDC, f = 300 KHz | | | | |
| | Tj = 22 °C | 28 | L. | 43 | V/V |
| | Tj = 0 °C | 28 | | 46 | V/V |
| | Tj = 110 °C | 22.2 | | 43 | V/V |
| Common Mode Rejection Ratio | Vin = 100 mVpp, 0VDC, f ≤ 5 MHz | 45 | | | dB |
| Power Supply Rejection Ratio | Vin = 0V, f \leq 5 MHz Δ VCC or Δ VEE = 100 mVpp | 45 | | | dB |
| Bandwidth | Zin = 0Ω , Vin = 1 mVPP, f midband = 300 KHz | 30 | | | MHz |
| Input Noise | Vin = 0V, Zin = 0Ω , Power Bandwidth = 15 MHz | | | 9.3 | μVRMS |
| Input Noise (SSI 32R104L) | Vin = 0V, Zin = 0Ω , Power Bandwidth = 15 MHz | | | 6.6 | μVRMS |
| Input Current | Vin = 0V | | | 26 | μА |
| Differential Input Capacitance | Vin = 0V | | | 23.5 | pF |
| Differential Input Resistance | Vin = 0V | | | | |
| | Tj = 22 °C | 585 | | 915 | Ω |
| | Tj = 0 °C | 565 | | 915 | Ω |
| | Tj = 110 °C | 585 | | 1070 | Ω |
| Output Offset Voltage | Zin = 0 | | | 120 | m∨ |
| Common Mode Output Voltage | Vin = 0 | -0.78 | | -0.32 | ٧ |
| Unsafe Current | Write Current = 0 mA | | | 0.1 | mA |
| | Write Current = -45 mA | 40 | | 45 | mA |
| Dynamic Range | DC input voltage where AC gain falls to 90% of 0VDC input value. Measured with 0.5 mVpp AC input, Tj = 30 °C | 2.0 | | | mVp |
| Channel Separation | Vin = 1 mVpp, 0VDC, f = 5 MHz 3 channels driven | 40 | | | dB |

WRITE MODE

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNIT |
|----------------------------|---|----------|-----|----------|------|
| Differential Input Voltage | | 0.175 | | | ٧ |
| Single Ended Input voltage | | -0.68 | | -0.45 | V |
| Write Current | | -45 | | | mA |
| Current Gain | IWC = -45 mA | 0.95 | | 1.0 | |
| Write Current Voltage | IWC = -45 mA | VEE+0.25 | | VEE+1.0V | V |
| Unsafe Voltage | IUS = +45 mA | 4 | | VCC +.3 | V |
| Head Center Tap Voltage | | 3.2 | | 3.8 | V |
| Differential Head Voltage | IWC = -45 mA, Lh = 10 μH | 5.7 | | 7.2 | Vp |
| Single Ended Head Voltage | IWC = -45 mA, unselected heads at 3.5V Selected Side of Selected Head Current = 0 mA | 0.0 | | 0.9 | V |
| | = 90 mA | 1.4+VCC | | 3.7+VCC | V |
| Unsafe Current | IWC = -30 mA, f = 2 MHz: | | | 1.0 | mA |
| | Lh = 9 μH, VUS = 5.0V - 6.3V, | 15 | | 45 | mA |
| | Lh = 0, IWC = 45 mA, Rh = ∞ one side of head only | 15 | | 45 | mA |
| Unselected Head Current | IWC = -45 mA, f = 2 MHz, Lh = 9.5 µH | | | 2.0 | mAp |
| DX DY Input Current | | -2.0 | | 2.0 | mA |

SWITCHING CHARACTERISTICS

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNIT |
|---|---|-----|-----|------|------|
| Idle to Read/Write Transition Time | | | | 0.5 | μs |
| Read/Write to Idle Transition Time | | | | 0.5 | μs |
| Read to Write Transition Time | | | | 0.5 | μs |
| Write To Read Transition Time | | | | 0.5 | μs |
| Head Select Switching Delay | | | | 50.0 | ns |
| Head Current Transition Time | IWC = -45 mA, Lh = 0, f = 5 MHz | | | 15 | ns |
| Head Current Switching Delay Time | IWC = -45 mA, Lh = 0, f = 5 MHz | | | 15 | ns |
| Head Current Switching Hysteresis | IWC = -45 mA, Lh = 0, f = 5 MHz Data rise and fall time ≤ 1 nSec | | | 2 | ns |
| Unsafe Switching Delay Time Delay Time | IWC = -30 mA, f = 2 MHz; Lh = 9 μH | | | 1 | μs |
| | Lh = 0 μH | 0.8 | | 5.1 | μs |

4-Channel Thin Film Read/Write Device

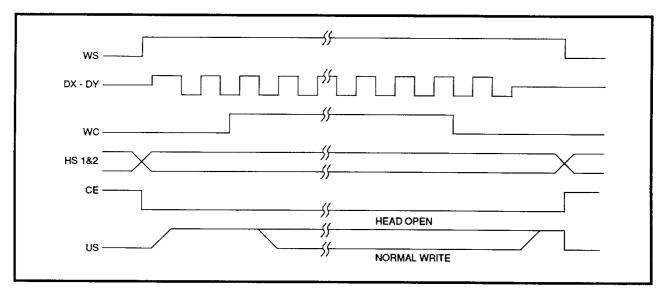
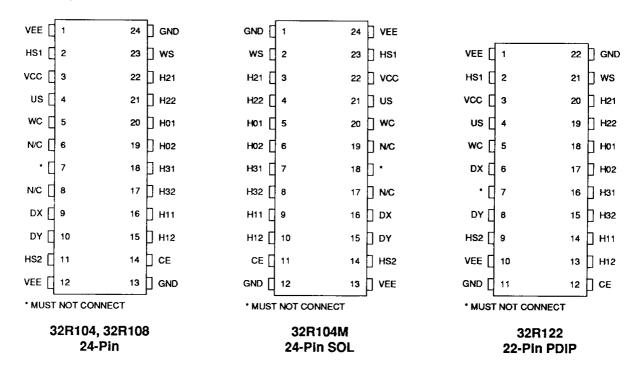


FIGURE 1: Write Mode Timing System

PACKAGE PIN DESIGNATIONS

(TOP VIEW)



THERMAL CHARACTERISTICS: Ø ja

| 22-Lead | PDIP | 65°C/W |
|---------|----------|---------|
| 24-Lead | PDIP | 115°C/W |
| 24-Lead | SOL | 80°C/W |
| 24-Lead | Flatpack | 105°C/W |

ORDERING INFORMATION

| PART DESCRIPTION | ORDERING NUMBER | PACKAGE MARK |
|---|-----------------|-----------------|
| SSI 32R104C Read/Write IC | | |
| 24-Lead Flatpack | SSI 32R104C-F | SSI 32R104C-F |
| 24-Lead SOL | SSI 32R104C-CL | SSI 32R104C-CL |
| SSI 32R104CL Low Noise Read/Write IC | | |
| 24-Lead Flatpack | SSI 32R104CL-F | SSI 32R104CL-F |
| SSI 32R104CM Mirror Image Read/Write IC | | |
| 24-Lead SOL | SSI 32R104CM-CL | SSI 32R104CM-CL |
| SSI 32R108 Read/Write IC | | |
| 24-Lead PDIP | SSI 32R108C-P | SSI 32R108C-P |
| SSI 32R122 Read/Write IC | • | |
| 22-Lead PDIP | SSI 32R122B-P | SSI 32R122B-P |

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